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CMOS Digital Integrated Circuits Silicon Monolithic

# 74HC373D

#### 1. Functional Description

- Octal D-Type Latch with 3-State Outputs

#### 2. General

The 74HC373D is a high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

These 8-bit D-type latches are controlled by a latch enable input (LE) and an output enable input ( $\overline{\text{OE}}$ ).

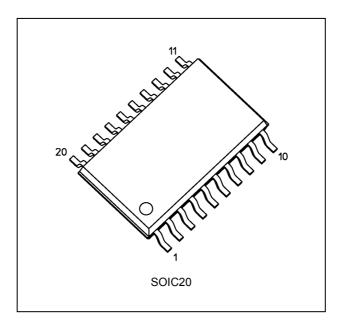
When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### 3. Features

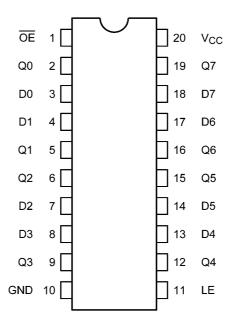
- (1) High speed:  $t_{pd} = 12 \text{ ns (typ.)}$  at  $V_{CC} = 6.0 \text{ V}$
- (2) Low power dissipation:  $I_{CC} = 4.0 \mu A \text{ (max)}$  at  $T_a = 25 \text{ °C}$
- (3) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (4) Wide operating voltage range:  $V_{CC(opr)} = 2.0 \text{ V}$  to 6.0 V

#### 4. Packaging

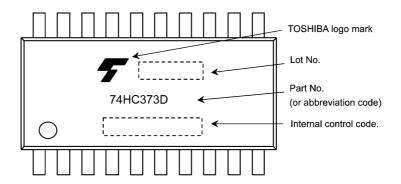




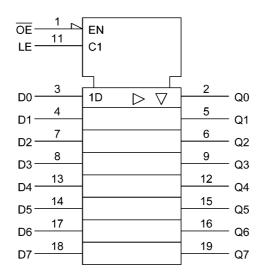
## 5. Pin Assignment



## 6. Marking



## 7. IEC Logic Symbol



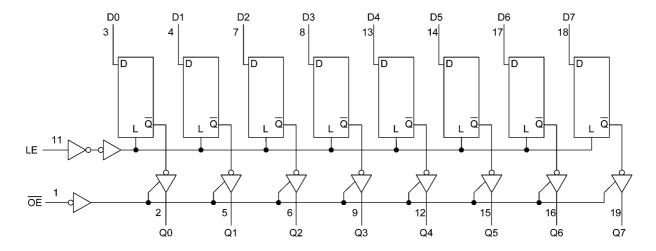
#### 8. Truth Table

INPUT OE	INPUT LE	INPUT D	OUTPUT Q
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't CareZ: High Impedance

Qn: Q outputs are latched at the time when the LE input is taken to low logic level.

## 9. System Diagram





#### 10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Output voltage	V <sub>OUT</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		±20	mA
Output diode current	I <sub>OK</sub>		±20	mA
Output current	I <sub>OUT</sub>		±35	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±75	mA
Power dissipation	P <sub>D</sub>	(Note 1)	500	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: PD derates linearly with -8 mW/°C above 85°C

#### 11. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>	_	2.0 to 6.0	V
Input voltage	V <sub>IN</sub>		0 to 5.5	V
Output voltage	V <sub>OUT</sub>	_	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>		-40 to 125	°C
Input rise and fall times	t <sub>r</sub> ,t <sub>f</sub>	_	0 to 50	μS

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.



#### 12. Electrical Characteristics

# 12.1. DC Characteristics (Unless otherwise specified, $T_a$ = 25 °C)

Characteristics	Symbol	Test Condition	1	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	_	V
				4.5	3.15	_	_	V
				6.0	4.20	_		V
Low-level input voltage	V <sub>IL</sub>	_		2.0			0.50	V
				4.5			1.35	V
				6.0			1.80	V
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH}$ = -20 $\mu$ A	2.0	1.9	2.0		V
				4.5	4.4	4.5	ı	
				6.0	5.9	6.0		
			$I_{OH}$ = -6 mA	4.5	4.18	4.31		
			$I_{OH} = -7.8 \text{ mA}$	6.0	5.68	5.80		
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	2.0		0.0	0.1	V
				4.5	_	0.0	0.1	
				6.0	_	0.0	0.1	
			$I_{OL}$ = 6 mA	4.5		0.17	0.26	
			I <sub>OL</sub> = 7.8 mA	6.0	_	0.18	0.26	V
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	I	ı	±0.5	μА
Input leakage current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND	_	6.0	_	_	±0.1	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND I <sub>O</sub> = 0 A		6.0	_	_	4.0	μА

## 12.2. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 85 °C)

Characteristics	Symbol	Test Condition	1	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	V
				4.5	3.15	_	
				6.0	4.20	_	V
Low-level input voltage	V <sub>IL</sub>	_		2.0		0.50	\ \
				4.5		1.35	
				6.0	_	1.80	V
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -20 μA	2.0	1.9	_	\ \
				4.5	4.4	_	
				6.0	5.9	_	
			I <sub>OH</sub> = -6 mA	4.5	4.13	_	
			$I_{OH} = -7.8 \text{ mA}$	6.0	5.63	_	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 20 μA	2.0		0.1	V
				4.5	_	0.1	
				6.0	_	0.1	
			I <sub>OL</sub> = 6 mA	4.5	_	0.33	
			I <sub>OL</sub> = 7.8 mA	6.0	_	0.33	V
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	l	±5.0	μА
Input leakage current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		6.0	_	±1.0	μА
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND $I_O = 0$ A		6.0	_	40.0	μА



## 12.3. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C)

Characteristics	Symbol	Test Condition	1	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	V
				4.5	3.15	_	
				6.0	4.20	_	V
Low-level input voltage	V <sub>IL</sub>	_		2.0	_	0.50	V
				4.5	_	1.35	
				6.0	_	1.80	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -20 μA	2.0	1.9	_	V
				4.5	4.4	_	
				6.0	5.9	_	
			I <sub>OH</sub> = -6 mA	4.5	3.7	_	
			I <sub>OH</sub> = -7.8 mA	6.0	5.2	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	2.0	_	0.1	V
				4.5	_	0.1	
				6.0	_	0.1	
			I <sub>OL</sub> = 6 mA	4.5	_	0.4	
			I <sub>OL</sub> = 7.8 mA	6.0	_	0.4	V
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	±10.0	μА
Input leakage current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		6.0	_	±1.0	μА
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND $I_{O} = 0$ A		6.0	_	160.0	μА



## 12.4. Timing Requirements (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width (LE)	t <sub>w(H)</sub>	_	2.0	75	ns
			4.5	15	
			6.0	13	
Minimum setup time (Dn)	t <sub>S</sub>	_	2.0	50	ns
			4.5	10	
			6.0	9	
Minimum hold time (Dn)	t <sub>h</sub>	_	2.0	5	ns
			4.5	5	
			6.0	5	

# 12.5. Timing Requirements (Unless otherwise specified, $T_a$ = -40 to 85 °C, Input: $t_r$ = $t_f$ = 6 ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width (LE)	t <sub>w(H)</sub>	_	2.0	95	ns
			4.5	19	
			6.0	16	
Minimum setup time (Dn)	t <sub>S</sub>	_	2.0	65	ns
			4.5	13	
			6.0	11	
Minimum hold time (Dn)	t <sub>h</sub>	_	2.0	5	ns
			4.5	5	
			6.0	5	

# 12.6. Timing Requirements (Unless otherwise specified, $T_a$ = -40 to 125 °C, Input: $t_r$ = $t_f$ = 6 ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width (LE)	t <sub>w(H)</sub>	_	2.0	120	ns
			4.5	24	
			6.0	20	
Minimum setup time (Dn)	t <sub>S</sub>	_	2.0	75	ns
			4.5	15	
			6.0	13	
Minimum hold time (Dn)	t <sub>h</sub>	_	2.0	5	ns
			4.5	5	
			6.0	5	



## 12.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Output transition time	t <sub>TLH</sub> ,t <sub>THL</sub>		_	2.0	50	_	20	60	ns
				4.5		_	6	12	
				6.0		_	5	10	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	2.0	50	_	42	125	ns
(LE-Q)				4.5		_	14	25	
				6.0		_	12	21	
				2.0	150	_	57	175	ns
				4.5			19	35	
				6.0			16	30	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	2.0	50	_	42	125	ns
(D-Q)				4.5			14	25	
				6.0			12	21	
				2.0	150	_	57	175	ns
				4.5			19	35	
				6.0			16	30	
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	2.0	50	_	39	125	ns
				4.5		_	13	25	
				6.0		_	11	21	
				2.0	150	_	54	175	ns
				4.5		_	18	35	
				6.0		_	15	30	
Output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>		$R_L = 1 k\Omega$	2.0	50	_	30	125	ns
				4.5			14	25	
				6.0		_	13	21	
Input capacitance	C <sub>IN</sub>					_	3	_	pF
Output capacitance	C <sub>OUT</sub>					_	4	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 1)				_	11	_	pF

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{|N} + I_{CC}/8 \text{ (per latch)}$ 



# 12.8. AC Characteristics (Unless otherwise specified, $T_a$ = -40 to 85 °C, Input: $t_f$ = $t_f$ = 6 ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Output transition time	t <sub>TLH</sub> ,t <sub>THL</sub>		_	2.0	50	_	75	ns
				4.5		_	15	
				6.0		_	13	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	2.0	50	_	155	ns
(LE-Q)				4.5		_	31	
				6.0		_	26	
				2.0	150	_	220	ns
				4.5		_	44	
				6.0		_	37	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	2.0	50	_	155	ns
(D-Q)				4.5		_	31	
				6.0		_	26	
				2.0	150	_	220	ns
				4.5		_	44	
				6.0		_	37	
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	2.0	50	_	155	ns
				4.5		_	31	
				6.0		_	26	
				2.0	150	_	220	ns
				4.5		_	44	
				6.0		_	37	
Output disable time	$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	2.0	50	_	155	ns
				4.5		_	31	
				6.0		_	26	



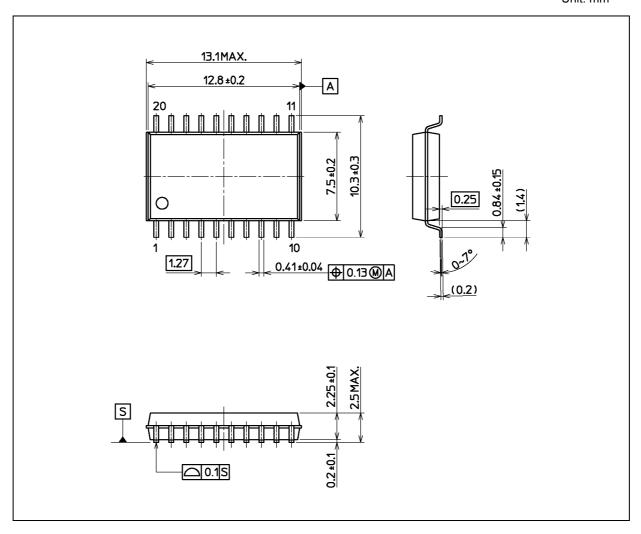
# 12.9. AC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C, Input: $t_r$ = $t_f$ = 6 ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Output transition time	t <sub>TLH</sub> ,t <sub>THL</sub>		_	2.0	50	_	90	ns
				4.5		_	18	
				6.0		_	15	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	2.0	50	_	190	ns
(LE-Q)				4.5		_	38	
				6.0		_	32	
				2.0	150	_	265	ns
				4.5		_	53	
				6.0		_	45	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	2.0	50	50 —	265	ns
(D-Q)				4.5		_	53	
				6.0		_	45	
				2.0	150	_	265	ns
				4.5		_	53	
				6.0		_	45	
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	2.0	50	_	225	ns
				4.5		_	45	
				6.0		_	38	
				2.0	150	_	265	ns
				4.5	1	_	53	
				6.0		_	45	
Output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>		R <sub>L</sub> = 1 kΩ	2.0	50	_	225	ns
				4.5		_	45	
				6.0		_	38	



## **Package Dimensions**

Unit: mm



Weight: 0.51 g (typ.)

	Package Name(s)
Nickname: SOIC20	



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